

MGA-68563

Current-Adjustable, Low Noise Amplifier



Data Sheet

Description

Avago Technologies MGA-68563 is an economical, easy-to-use GaAs MMIC amplifier that offers excellent linearity and low noise figure for applications from 0.1 to 1.5 GHz. Packaged in an miniature SOT-363 package, it requires half the board space of a SOT-143 package.

One external resistor is used to set the bias current from 5mA to 30mA. This allows the designer to use the same part in several circuit positions and tailor the linearity performance (and current consumption) to suit each position.

The output of the amplifier is matched to 50Ω (below 2:1 VSWR) across the entire bandwidth and only requires minimum input matching. The amplifier allows a wide dynamic range by offering a 1.0 dB NF coupled with a +20 dBm Output IP3. The circuit uses state-of-the-art E-pHEMT technology with proven reliability. On-chip bias circuitry allows operation from a single +3V power supply, while internal feedback ensures stability ($K > 1$) over all frequencies for I_d at 10mA and above.

Features

- Single +3V supply
- High linearity
- Low noise figure
- Miniature package
- Unconditionally stable

Specifications at 500 MHz; 3V, 10 mA (Typ.)

- 1.0 dB noise figure
- 20 dBm OIP3
- 19.7 dB gain
- * This represents what Avago Technologies has managed to achieve on a device level with trade off between optimal NF, Gain, OIP3 and input return loss.

Applications

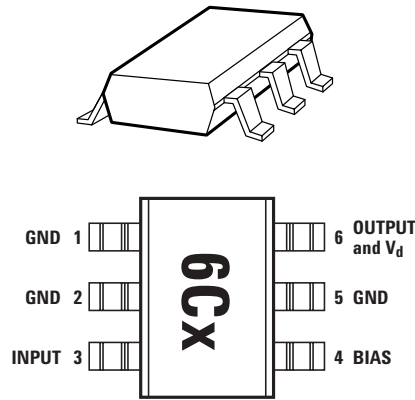
- LNA for DVB-T, DVB-H, T-DMB, ISDB-T, DAB and MediaFLO



Attention:
Observe precautions for
handling electrostatic
sensitive devices.

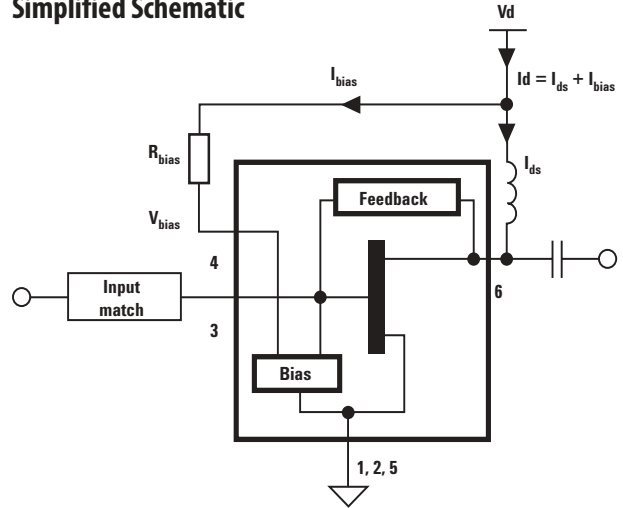
ESD Machine Model (Class A)
ESD Human Body Model (Class 1A)
Refer to Agilent Application Note A004R:
Electrostatic Discharge Damage and Control.

Pin Connections and Package Marking



Note:
Package marking provides orientation and identification:
"6C" = Device Code
"x" = Date code indicates the month of manufacture.

Simplified Schematic



MGA-68563 Absolute Maximum Ratings^[1]

Symbol	Parameter	Units	Absolute Maximum
V_d	Device Voltage (pin 6) ^[2]	V	6
I_d	Device Current (pin 6) ^[2]	mA	100
P_{in}	CW RF Input Power (pin 3) ^[3]	dBm	21
I_{ref}	Bias Reference Current (pin 4)	mA	12
P_{diss}	Total Power Dissipation ^[4]	mW	600
T_{CH}	Channel Temperature	°C	150
T_{STG}	Storage Temperature	°C	150
θ_{ch_b}	Thermal Resistance ^[5]	°C/W	97

Notes:

1. Operation of this device above any one of these parameters may cause permanent damage.
2. Bias is assumed at DC quiescent conditions.
3. With the DC (typical bias) and RF applied to the device at board temperature $T_B = 25^\circ\text{C}$.
4. Total dissipation power is referred to lead "5" temperature. $T_c=92^\circ\text{C}$, derate P_{diss} at $10.3\text{mW}/^\circ\text{C}$ for $T_c>92^\circ\text{C}$.
5. Thermal resistance measured using 150°C Liquid Crystal Measurement method.

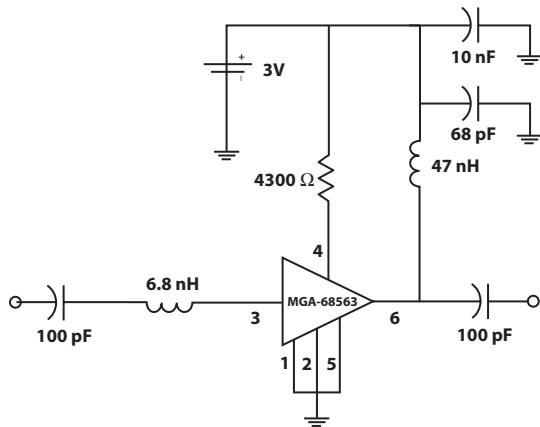


Figure 1a. Test circuit of the 0.5 GHz production test board used for NF, Gain and OIP3 measurements. This circuit achieves a trade-off between optimal NF, Gain, OIP3 and input return loss. Circuit losses have been de-embedded from actual measurements.

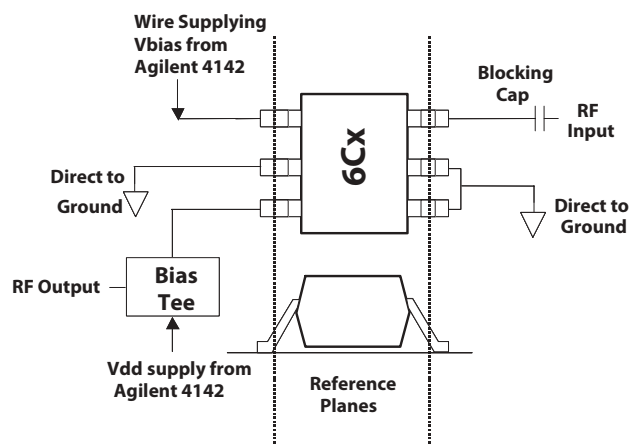


Figure 1b. A diagram showing the connection to the DUT during an S and Noise parameter measurement using an automated tuner system.

MGA-68563 Electrical Specifications

$T_C = 25^\circ\text{C}$, $Z_O = 50\Omega$, $V_d = 3\text{V}$ (unless otherwise specified)

Symbol	Parameters and Test Conditions	Freq	Units	Min.	Typ.	Max.
$I_d^{[1,2]}$	Device Current		mA		11	16
$NF_{\text{test}}^{[1,2]}$	Noise Figure in test circuit ^[1]	$f = 0.5\text{ GHz}$	dB		1.0	1.4
$G_{\text{test}}^{[1,2]}$	Associated Gain in test circuit ^[1]	$f = 0.5\text{ GHz}$	dB	18	19.7	21.5
$OIP3_{\text{test}}^{[1,2]}$	Output 3 rd Order Intercept in test circuit ^[1]	$f = 0.5\text{ GHz}$	dBm	18	20.7	
$P1dB_{\text{test}}^{[1,2]}$	Output Power at 1dB Gain Compression in test circuit. ^[1]	$f = 0.5\text{ GHz}$	dBm		17.5	

Notes:

- Guaranteed specifications are 100% tested in the production test circuit, the typical value is based on measurement of at least 600 parts from two non-consecutive wafer lots during initial characterization of this product.
- Circuit achieved a trade-off between optimal NF, Gain, OIP3 and input return loss.

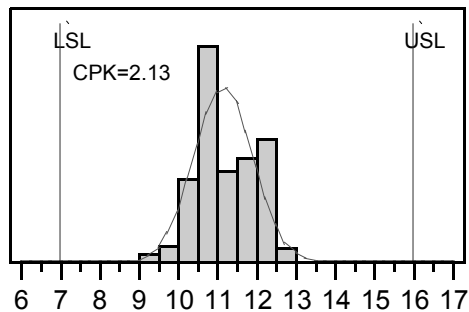


Figure 2. I_d @ 3V. LSL=7, Nominal=11, USL=16

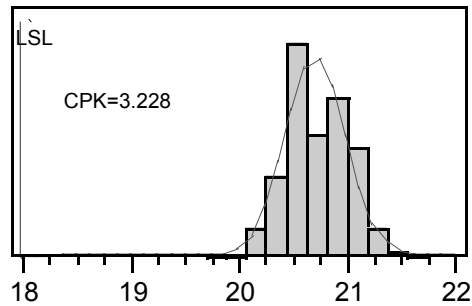


Figure 3. $OIP3$ @ 0.5GHz 3V. LSL=18, Nominal=20.7

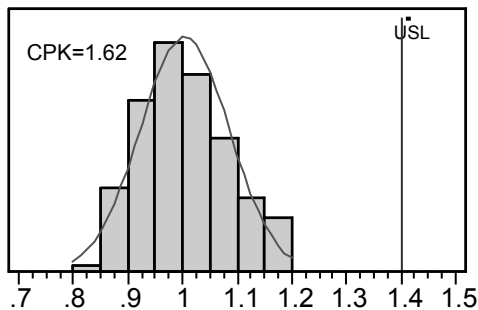


Figure 4. NF @ 0.5GHz 3V. USL=1.4, Nominal=1.0

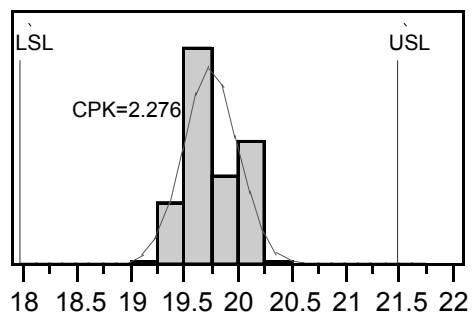


Figure 5. $Gain$ @ 0.5GHz 3V. USL=18, Nominal=19.7, USL=21.5

Note:

Measured on the production circuit.

Distribution data sample size is 600 samples taken from 2 non-consecutive wafer lots. Future wafers allocated to this product may have nominal values anywhere between upper and lower limits.

MGA-68563 Typical Performance, Vd = 3V, Ids = 5mA at 50ohm Input and Output

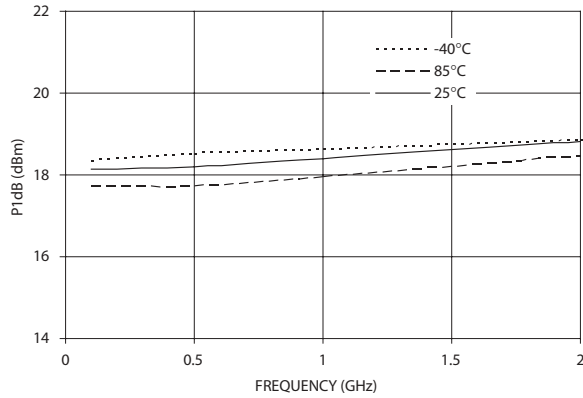


Figure 6. OP1dB vs. Frequency (3V 5mA)

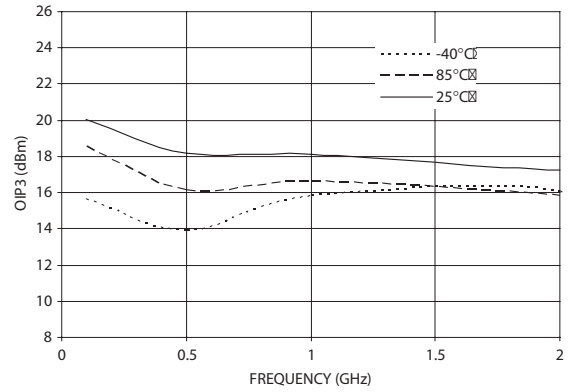


Figure 7. OIP3 vs. Frequency (3V 5mA)

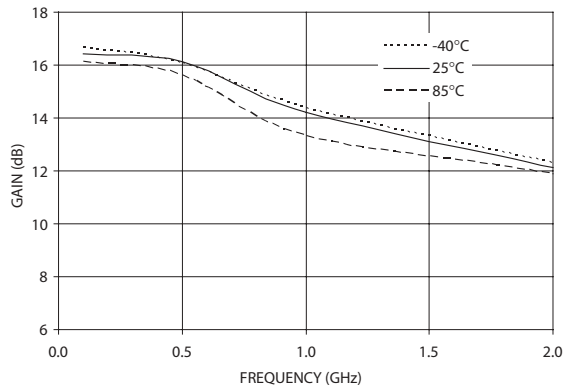


Figure 8. Gain vs. Frequency (3V 5mA)

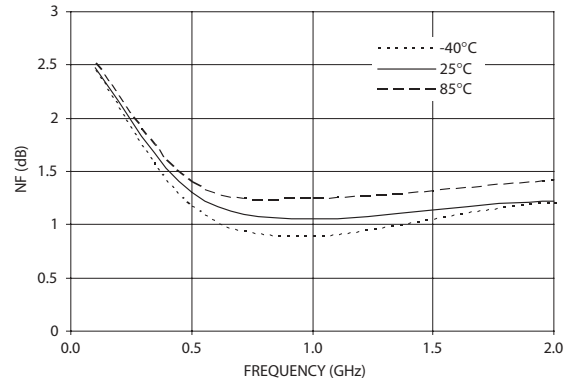


Figure 9. NF vs. Frequency (3V 5mA)

Notes:

1. Ids taken @ ambient temperature of 25°C may change with temperature variation.
2. Bias current (Ids) for the above charts are quiescent conditions. Actual level may increase or decrease depending on amount of RF drive.

MGA-68563 Typical Performance, Vd = 3V, Ids = 10mA at 50ohm Input and Output

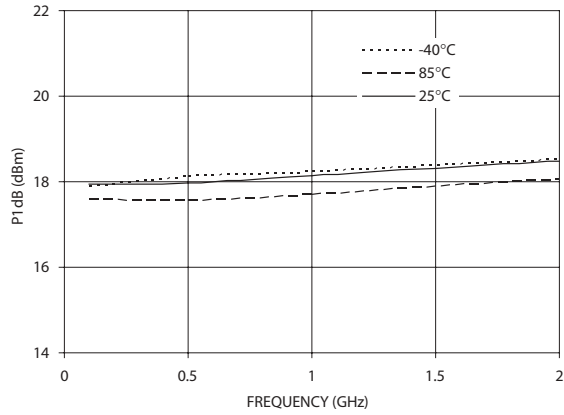


Figure 10. OP1dB vs. Frequency (3V 10mA)

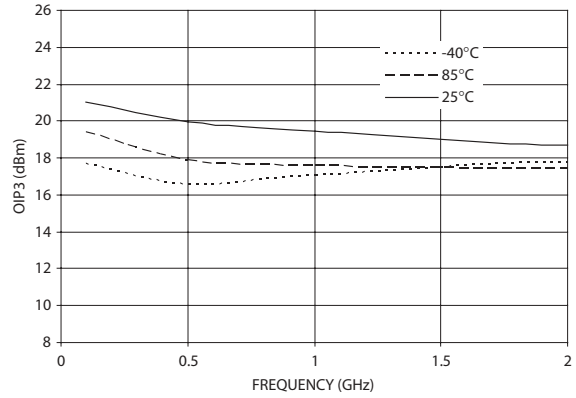


Figure 11. OIP3 vs. Frequency (3V 10mA)

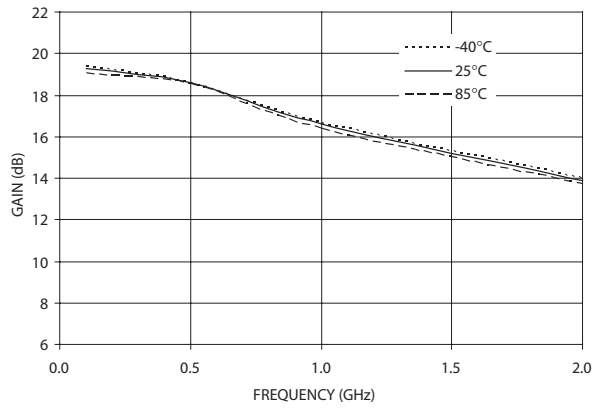


Figure 12. Gain vs. Frequency (3V 10mA)

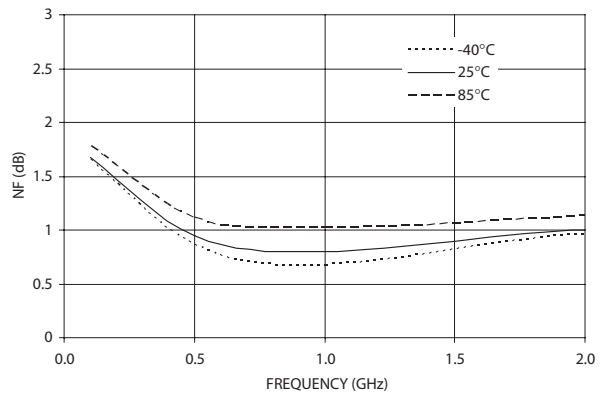


Figure 13. NF vs. Frequency (3V 10mA)

Notes:

1. Ids taken @ ambient temperature of 25°C may change with temperature variation.
2. Bias current (Ids) for the above charts are quiescent conditions. Actual level may increase or decrease depending on amount of RF drive.

MGA-68563 Typical Performance, Vd = 3V, Ids = 15mA at 50ohm Input and Output

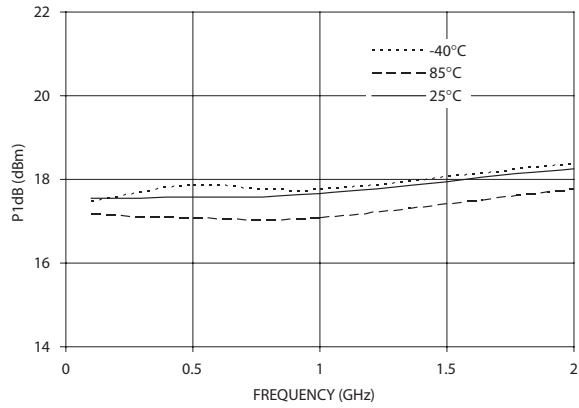


Figure 14. OP1dB vs. Frequency (3V 15mA)

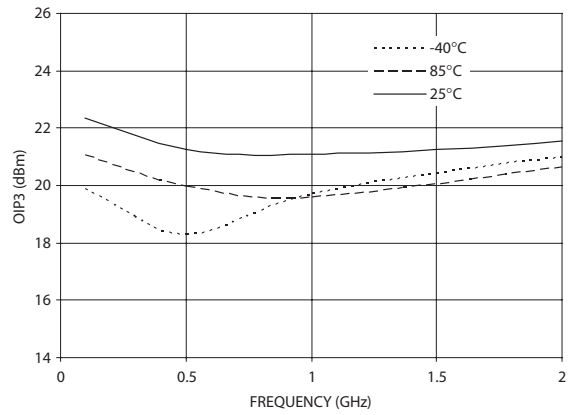


Figure 15. OIP3 vs. Frequency (3V 15mA)

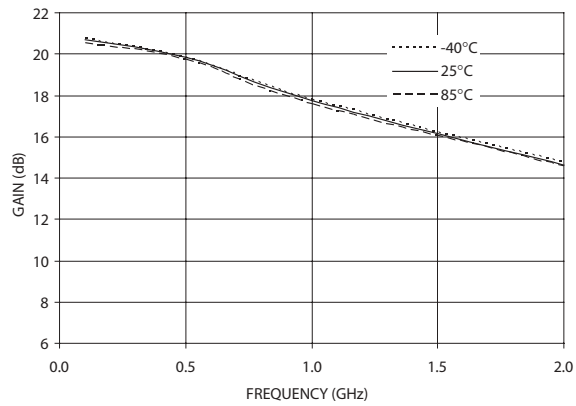


Figure 16. Gain vs. Frequency (3V 15mA)

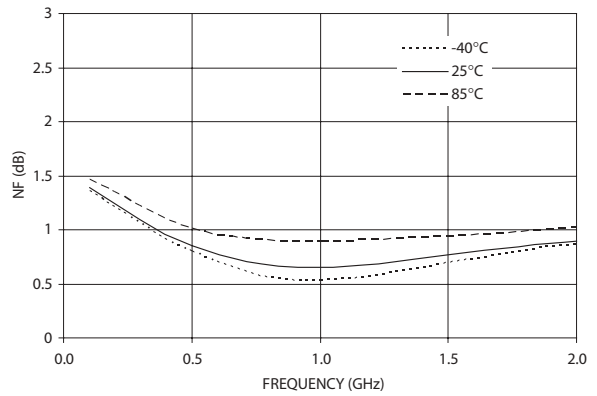


Figure 17. NF vs. Frequency (3V 15mA)

Notes:

1. Ids taken @ ambient temperature of 25°C may change with temperature variation.
2. Bias current (Ids) for the above charts are quiescent conditions. Actual level may increase or decrease depending on amount of RF drive.

MGA-68563 Typical Performance, Vd = 5V, Ids = 5mA at 50ohm Input and Output

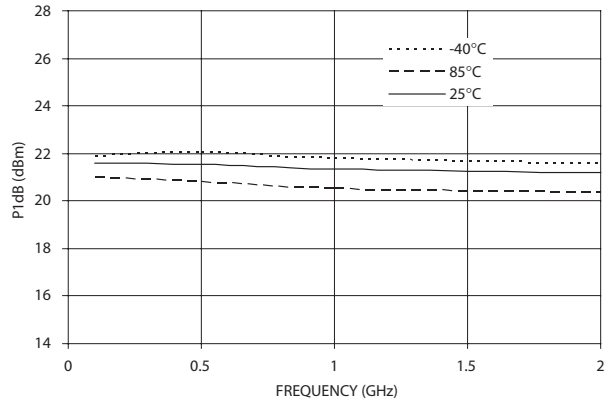


Figure 18. OP1dB vs. Frequency (5V 5mA)

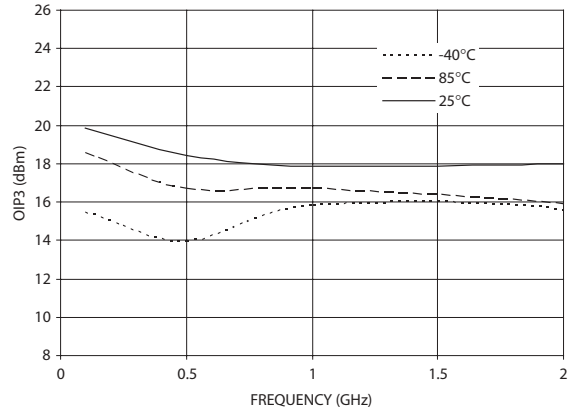


Figure 19. OIP3 vs. Frequency (5V 5mA)

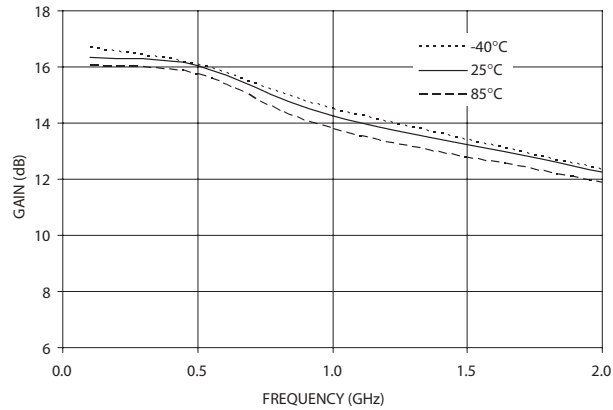


Figure 20. Gain vs. Frequency (5V 5mA)

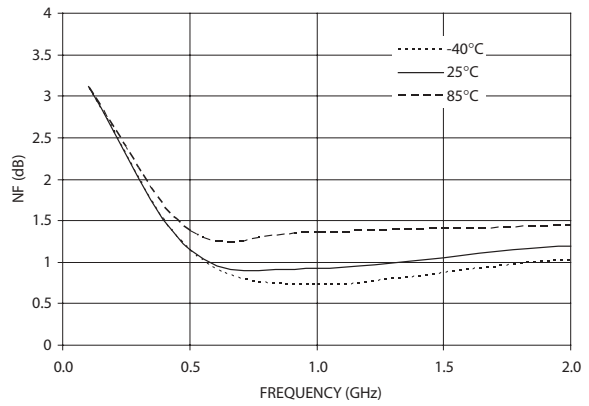


Figure 21. NF vs. Frequency (5V 5mA)

Notes:

1. Ids taken @ ambient temperature of 25°C may change with temperature variation.
2. Bias current (Ids) for the above charts are quiescent conditions. Actual level may increase or decrease depending on amount of RF drive.

MGA-68563 Typical Performance, Vd = 5V, Ids = 10mA at 50ohm Input and Output

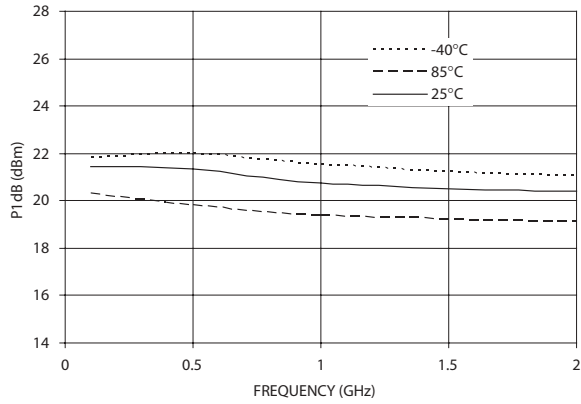


Figure 22. OP1dB vs. Frequency (5V 10mA)

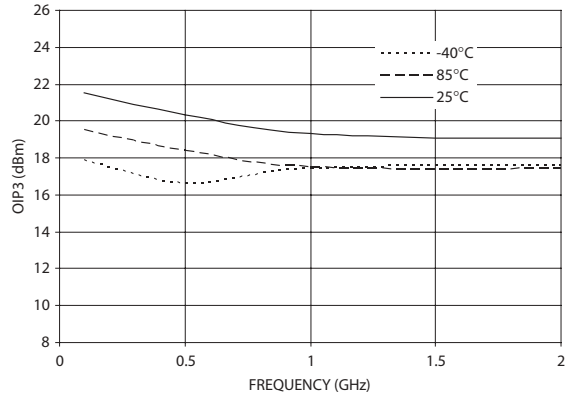


Figure 23. OIP3 vs. Frequency (5V 10mA)

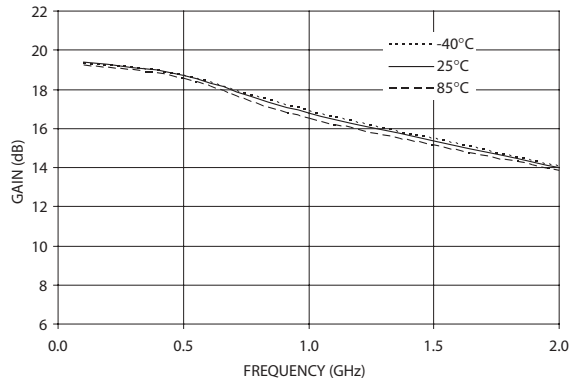


Figure 24. Gain vs. Frequency (5V 10mA)

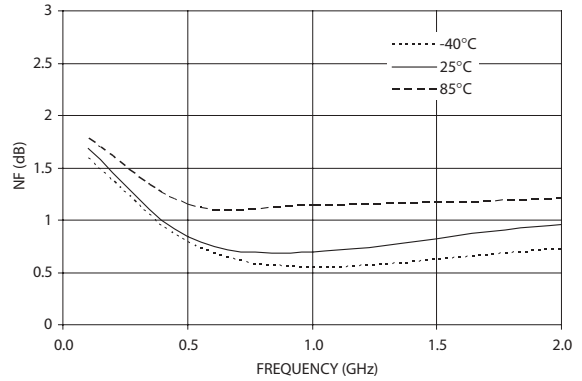


Figure 25. NF vs. Frequency (5V 10mA)

Notes:

1. Ids taken @ ambient temperature of 25°C may change with temperature variation.
2. Bias current (Ids) for the above charts are quiescent conditions. Actual level may increase or decrease depending on amount of RF drive.

MGA-68563 Typical Performance, Vd = 5V, Ids = 15mA at 50ohm Input and Output

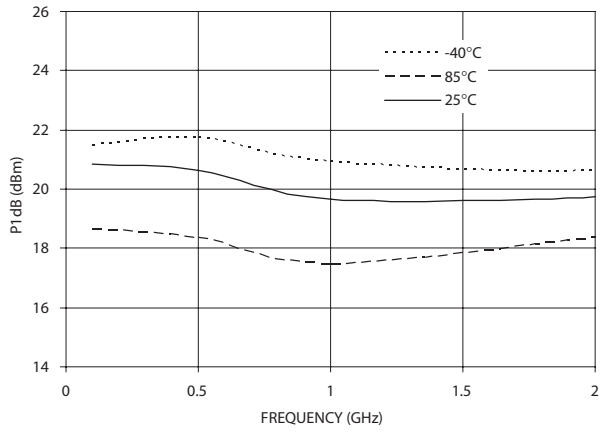


Figure 26. OP1dB vs. Frequency (5V 15mA)

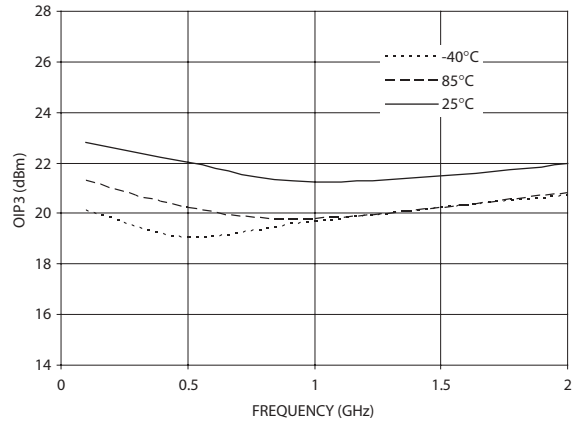


Figure 27. OIP3 vs. Frequency (5V 15mA)

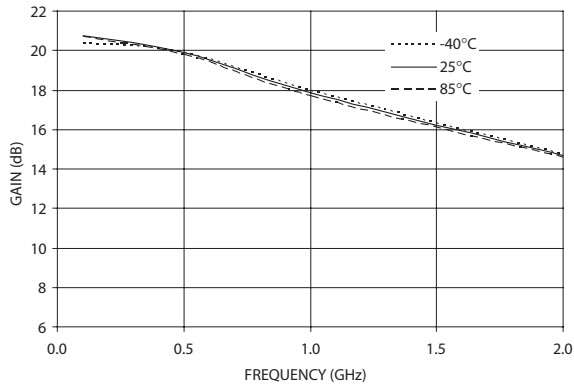


Figure 28. Gain vs. Frequency (5V 15mA)

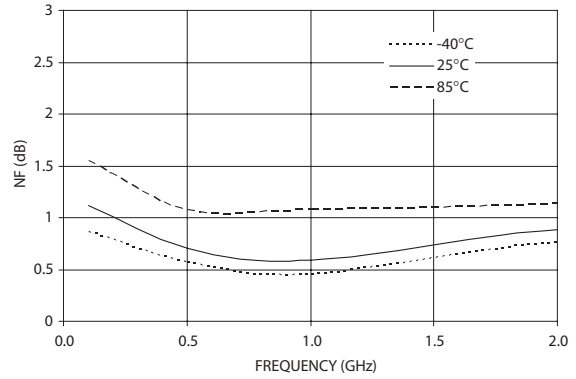


Figure 29. NF vs. Frequency (5V 15mA)

Notes:

1. Ids taken @ ambient temperature of 25°C may change with temperature variation.
2. Bias current (Ids) for the above charts are quiescent conditions. Actual level may increase or decrease depending on amount of RF drive.

MGA-68563 Typical Performance, Freq = 0.5GHz, Tc = 25°C at 50ohm Input and Output

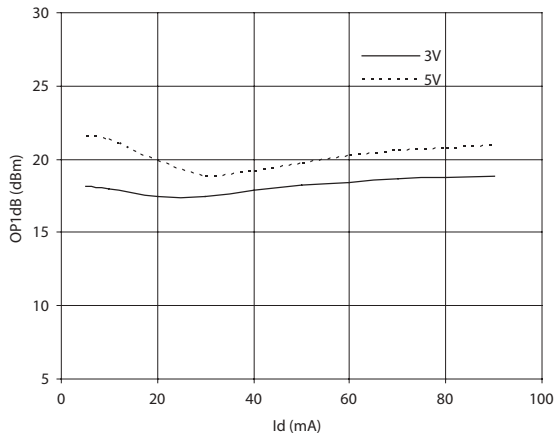


Figure 30. OP1dB vs. Id (500 MHz)

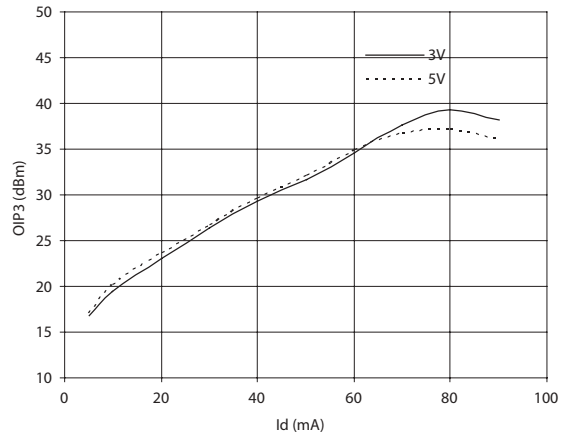


Figure 31. OIP3 vs. Id (500 MHz)

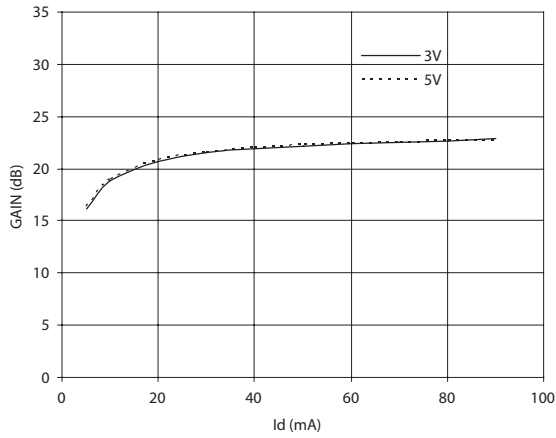


Figure 32. Gain vs. Id (500 MHz)

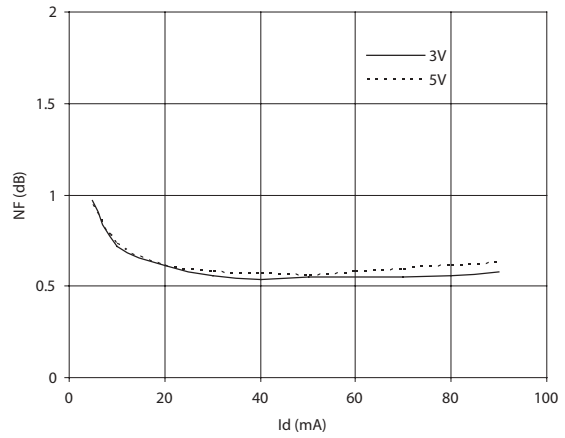


Figure 33. NF vs. Id (500 MHz)

Notes:

1. Bias current (Ids) for the above charts are quiescent conditions. Actual level may increase or decrease depending on amount of RF drive.

MGA-68563 Typical Performance, Freq = 0.1GHz, Tc = 25°C at 50ohm Input and Output

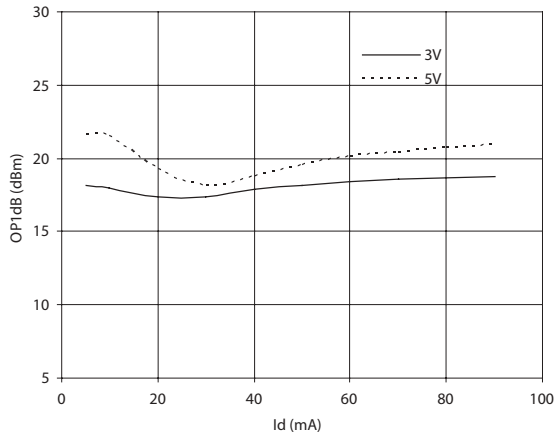


Figure 34. OP1dB vs. Id (100 MHz)

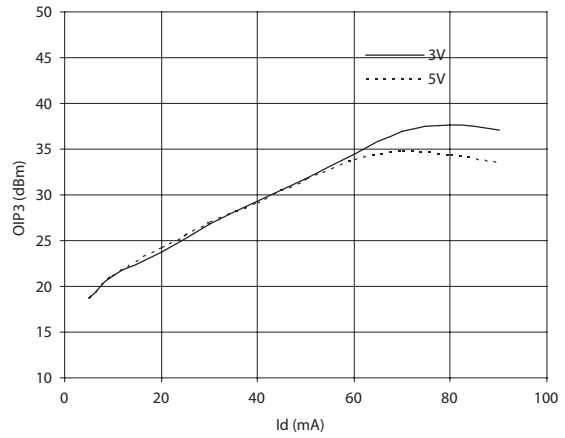


Figure 35. OIP3 vs. Id (100 MHz)

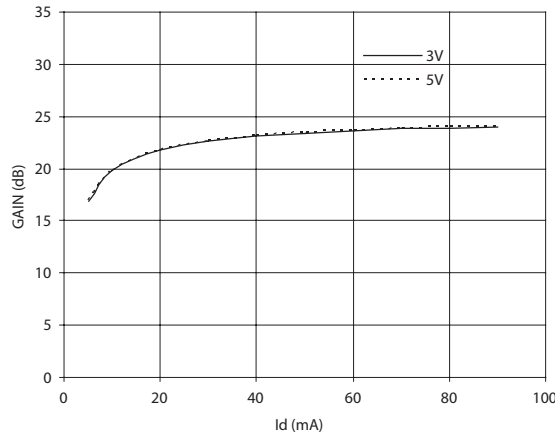


Figure 36. Gain vs. Id (500 MHz)

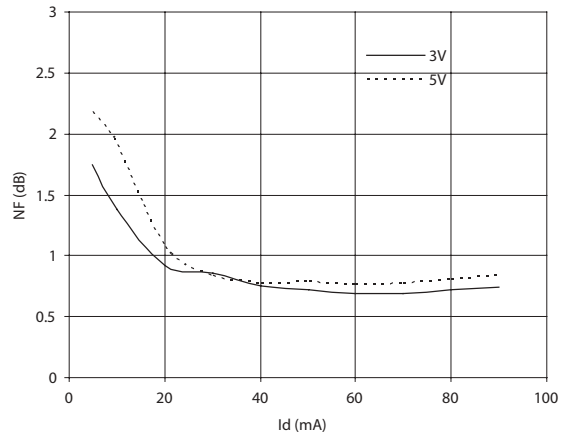


Figure 37. NF vs. Id (500 MHz)

Notes:

1. Bias current (Ids) for the above charts are quiescent conditions. Actual level may increase or decrease depending on amount of RF drive.

MGA-68563 Typical Performance, Freq = 0.5GHz, I_{ds} = 10mA, T_c=25°C at 50ohm Input and Output

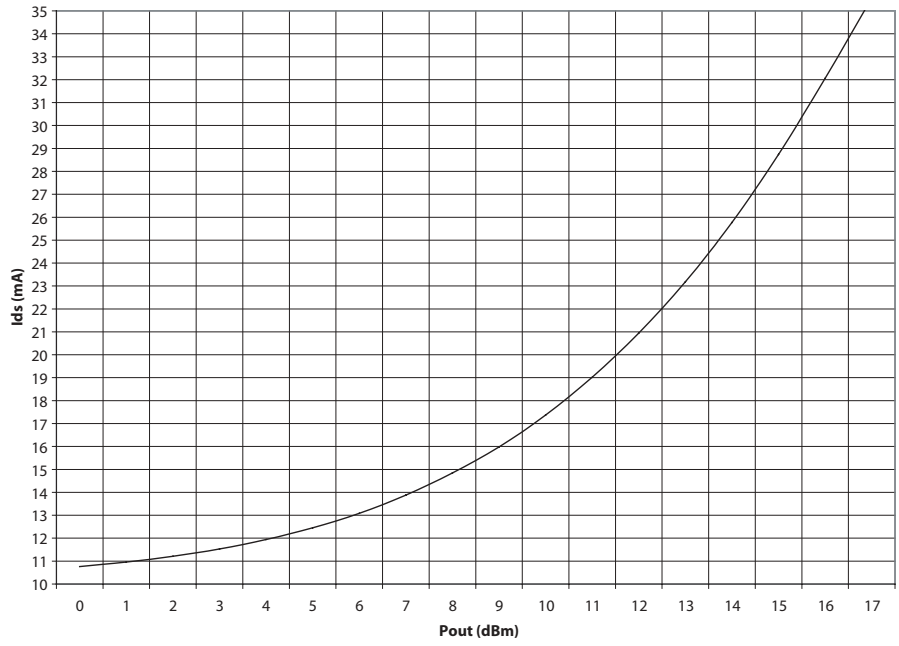


Figure 39. Ids vs. Pout (Vd = 3V)

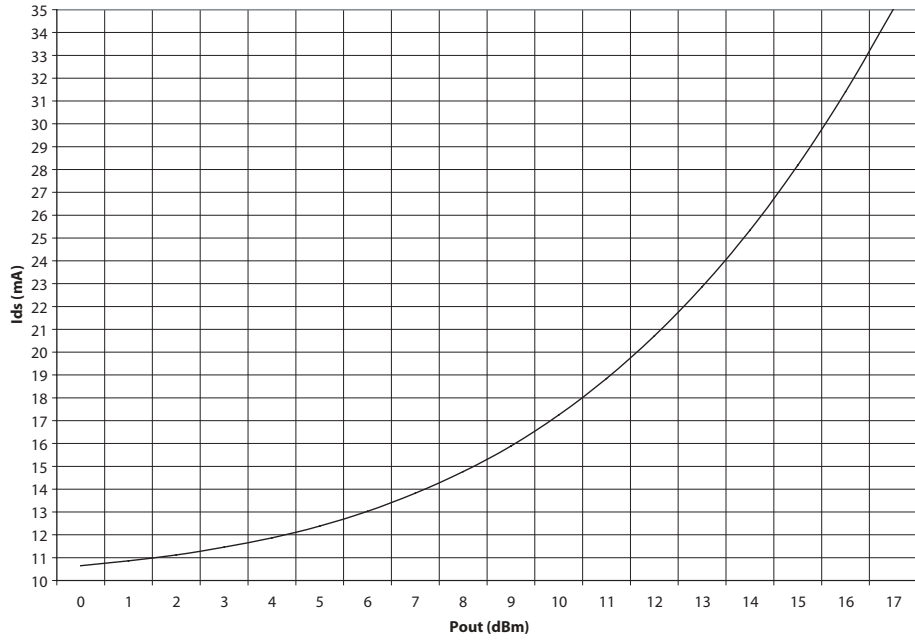


Figure 38. Ids vs. Pout (Vd = 5V)

Notes:

1. Bias current (I_{ds} = 10mA) for the above charts are quiescent conditions.

MGA-68563 Typical Scattering Parameters, Tc = 25°C, Zo = 50ohm, Vd = 3V, Ids = 10mA

Freq.	S11		S21			S12		S22		K-factor
	GHz	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	Mag.	
0.3	0.42	-37.10	19.26	9.18	158.40	0.07	5.40	0.27	-32.20	1.01
0.5	0.36	-57.20	18.81	8.72	145.00	0.07	3.80	0.19	-47.50	1.04
0.7	0.38	-76.30	18.16	8.09	133.90	0.07	3.90	0.19	-63.10	1.02
0.9	0.40	-92.50	17.43	7.44	123.90	0.07	4.10	0.18	-75.80	1.03
1.0	0.41	-99.70	17.07	7.14	119.30	0.07	4.10	0.17	-81.80	1.03
1.1	0.42	-106.70	16.70	6.84	115.00	0.07	4.20	0.17	-86.30	1.04
1.3	0.44	-119.50	16.00	6.31	106.80	0.07	4.40	0.16	-95.10	1.04
1.5	0.45	-132.30	15.36	5.86	99.40	0.07	4.50	0.17	-98.30	1.06
1.7	0.47	-141.10	14.71	5.44	92.30	0.07	4.60	0.16	-107.70	1.08
1.9	0.48	-150.50	14.09	5.06	85.60	0.08	4.60	0.15	-115.30	1.11
2.0	0.49	-154.60	13.81	4.90	82.50	0.08	4.60	0.15	-116.20	1.11
2.5	0.51	-176.40	12.46	4.20	67.00	0.08	3.10	0.14	-131.90	1.16
3.0	0.50	160.80	11.13	3.60	53.80	0.09	2.00	0.15	-153.10	1.28
3.5	0.50	142.70	10.13	3.21	41.80	0.09	0.30	0.15	-176.10	1.35
4.0	0.51	126.90	9.74	3.07	25.20	0.11	-8.60	0.08	162.40	1.29

Typical Noise Parameters at 25°C,

Tc = 25°C, Zo = 50ohm, Vd = 3V, Ids = 10mA

Freq.	Fmin	Γopt		Rn/50	NF@50Ω
		Mag.	Ang.		dB
GHz	dB				
0.5	0.83	0.12	108.80	0.11	0.85
1.0	0.74	0.05	109.80	0.08	0.74
1.5	0.76	0.16	151.40	0.07	0.80
2.0	0.88	0.21	147.90	0.07	0.94
2.5	1.05	0.24	161.50	0.06	1.12
3.0	1.24	0.26	-173.10	0.09	1.31

MGA-68563 Typical Scattering Parameters, Tc = 25°C, Zo = 50ohm, Vd = 3V, Ids = 5mA

Freq.	S11		S21			S12		S22		K-factor
	GHz	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	Mag.	
0.3	0.54	-28.80	16.61	6.77	160.50	0.07	6.50	0.43	-24.60	1.01
0.5	0.47	-44.40	16.31	6.54	147.20	0.08	4.20	0.35	-36.80	1.02
0.7	0.48	-60.80	15.77	6.15	136.80	0.08	4.00	0.33	-49.10	1.00
0.9	0.48	-75.60	15.15	5.72	127.10	0.08	3.60	0.31	-59.50	0.98
1.0	0.48	-82.30	14.85	5.53	122.60	0.08	3.10	0.30	-64.30	0.98
1.1	0.49	-89.20	14.53	5.33	118.40	0.08	2.80	0.29	-68.50	0.98
1.3	0.50	-102.00	13.93	4.97	110.30	0.09	2.00	0.28	-76.00	0.98
1.5	0.50	-114.50	13.37	4.66	102.90	0.09	1.10	0.28	-81.10	0.98
1.7	0.52	-124.30	12.82	4.38	95.80	0.09	0.10	0.25	-88.20	0.98
1.9	0.52	-134.20	12.27	4.11	88.90	0.09	-1.10	0.24	-94.80	1.01
2.0	0.53	-138.60	12.03	3.99	85.70	0.09	-1.50	0.23	-96.00	1.02
2.5	0.55	-162.10	10.86	3.49	69.70	0.10	-5.30	0.21	-110.40	1.07
3.0	0.53	173.50	9.61	3.02	55.60	0.10	-8.00	0.20	-127.80	1.23
3.5	0.51	153.90	8.67	2.71	42.90	0.10	-10.40	0.18	-146.80	1.35
4.0	0.53	137.40	8.38	2.62	26.70	0.11	-18.20	0.12	-153.40	1.32

Typical Noise Parameters at 25°C,

Tc = 25°C, Zo = 50ohm, Vd = 3V, Ids = 5mA

Freq.	Fmin	Γopt		Rn/50	NF@50Ω
		Mag.	Ang.		dB
0.5	1.21	0.15	97.70	0.14	1.25
1.0	1.01	0.12	62.80	0.11	1.03
1.5	1.04	0.18	114.20	0.11	1.10
2.0	1.07	0.24	123.90	0.09	1.17
2.5	1.20	0.28	141.00	0.08	1.33
3.0	1.41	0.29	162.20	0.10	1.50

MGA-68563 Typical Scattering Parameters, Tc = 25°C, Zo = 50ohm, Vd = 3V, Ids = 15mA

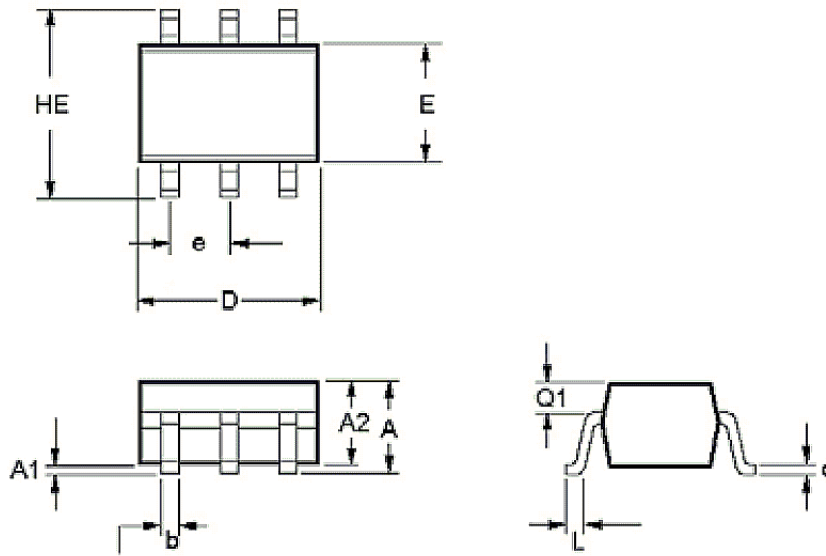
Freq.	S11		S21			S12		S22		K-factor
	GHz	Mag.	Ang.	dB	Mag.	Ang.	Mag.	Ang.	Mag.	
0.3	0.35	-43.60	20.54	10.64	157.30	0.06	5.00	0.18	-41.30	1.01
0.5	0.30	-67.40	19.99	9.99	143.70	0.06	3.90	0.11	-64.30	1.04
0.7	0.33	-87.40	19.27	9.20	132.40	0.06	4.40	0.12	-82.80	1.05
0.9	0.36	-103.80	18.49	8.41	122.20	0.06	5.30	0.12	-96.80	1.06
1.0	0.37	-110.90	18.10	8.03	117.60	0.06	5.60	0.12	-103.50	1.07
1.1	0.39	-117.60	17.70	7.68	113.20	0.06	6.10	0.12	-107.50	1.07
1.3	0.41	-129.90	16.95	7.04	105.00	0.06	7.10	0.12	-116.50	1.10
1.5	0.43	-142.10	16.26	6.50	97.60	0.06	7.90	0.12	-116.30	1.12
1.7	0.46	-150.20	15.57	6.00	90.70	0.07	8.60	0.12	-127.30	1.13
1.9	0.46	-159.10	14.91	5.56	84.00	0.07	9.10	0.12	-134.70	1.17
2.0	0.47	-162.90	14.61	5.38	81.00	0.07	9.30	0.11	-135.30	1.16
2.5	0.50	176.50	13.19	4.56	65.80	0.08	8.70	0.12	-149.80	1.20
3.0	0.50	154.70	11.82	3.90	53.00	0.08	7.90	0.14	-170.30	1.30
3.5	0.50	137.50	10.80	3.47	41.40	0.09	5.90	0.15	167.50	1.33
4.0	0.50	122.10	10.35	3.29	24.70	0.11	-3.90	0.09	137.50	1.27

Typical Noise Parameters at 25°C,

Tc = 25°C, Zo = 50ohm, Vd = 3V, Ids = 15mA

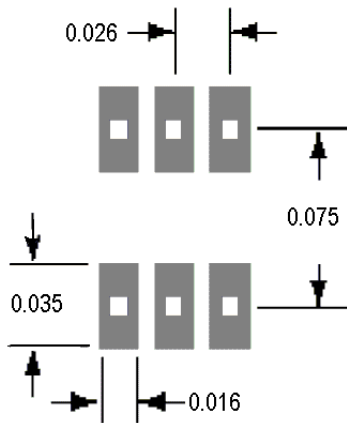
Freq.	Fmin	Γopt		Rn/50	NF@50Ω
		Mag.	Ang.		dB
0.5	0.65	0.10	119.90	0.09	0.66
1.0	0.55	0.06	158.20	0.07	0.56
1.5	0.59	0.13	163.00	0.07	0.62
2.0	0.81	0.21	160.60	0.06	0.86
2.5	0.99	0.22	172.00	0.06	1.05
3.0	1.17	0.25	-163.70	0.09	1.22

SOT-363/SC-70 (JEDEC DFP-N) Package Dimensions



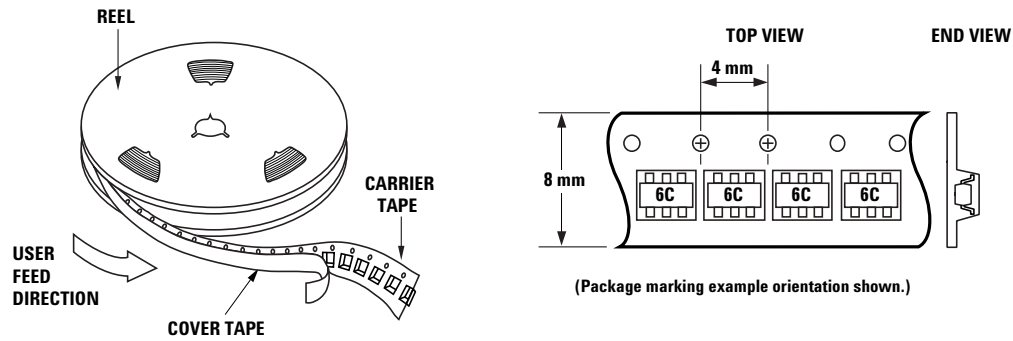
Symbol	Dimensions	
	Min (mm)	Max (mm)
E	1.15	1.35
D	1.80	2.25
HE	1.80	2.40
A	0.80	1.10
A2	0.80	1.00
A1	0.00	0.10
e	0.650 BCS	0.650 BCS
b	0.15	0.30
c	0.10	0.20
L	0.10	0.30

Recommended PCB Pad Layout for Avago Technologies SC70 6L/SOT-363 Products

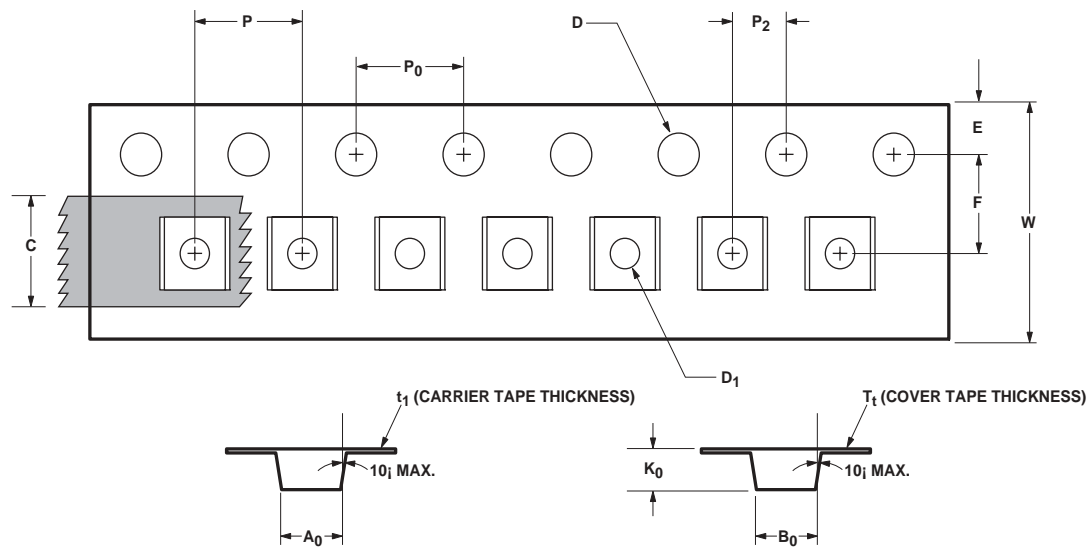


(dimensions in inches)

Device Orientation



Tape Dimensions



	DESCRIPTION	SYMBOL	SIZE (mm)	SIZE (INCHES)
CAVITY	LENGTH	A ₀	2.40 ± 0.10	0.094 ± 0.004
	WIDTH	B ₀	2.40 ± 0.10	0.094 ± 0.004
	DEPTH	K ₀	1.20 ± 0.10	0.047 ± 0.004
	PITCH	P	4.00 ± 0.10	0.157 ± 0.004
	BOTTOM HOLE DIAMETER	D ₁	1.00 ± 0.25	0.039 ± 0.010
PERFORATION	DIAMETER	D	1.50 ± 0.10	0.061 ± 0.002
	PITCH	P ₀	4.00 ± 0.10	0.157 ± 0.004
	POSITION	E	1.75 ± 0.10	0.069 ± 0.004
CARRIER TAPE	WIDTH	W	8.00 ± 0.30 - 0.10	0.315 ± 0.012
	THICKNESS	t ₁	0.254 ± 0.02	0.010 ± 0.0005
COVER TAPE	WIDTH	C	5.40 ± 0.10	0.205 ± 0.004
	TAPE THICKNESS	T _t	0.062 ± 0.001	0.0025 ± 0.00004
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION)	F	3.50 ± 0.05	0.138 ± 0.002
	CAVITY TO PERFORATION (LENGTH DIRECTION)	P ₂	2.00 ± 0.05	0.079 ± 0.002

Ordering Information

Part No.	No. of Devices	Container
MGA-68563-TR1G	3000	7" Reel
MGA-68563-TR2G	10000	13" Reel
MGA-68563-BLKG	100	antistatic bag

For product information and a complete list of distributors, please go to our web site: www.avagotech.com

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